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Emerging NO₂ gas sensing on substitutionally doped Fe on NiWO₄ SCES insulators

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In this study, we demonstrate the emergence of NO₂ gas sensing capabilities in the typically non-active NiWO₄, a strongly correlated electron system (SCES), by introducing substitutional Fe at the Ni site. NiWO₄ typically exhibits strong Coulombic repulsion between Ni atoms, resulting in a large band gap of over 3.0 eV and insulating behavior. This correlated behavior is clearly reflected in the significant increase of band gap when considering the Hubbard Ucorrection for the cations, bringing the theoretical value closer to the observed value. The single-phase $Fe_{0.5}Ni_{0.5}WO_4$ displays a notable shift in the [NiO₆] symmetric vibration mode and an increase in magnetization. Additionally, theoretical calculations confirm the preservation of the wide band gap, with the Fe and O levels generated within the band gap. These findings indicate that Fe located in the Ni sites modulate Coulombic repulsion in NiWO₄ SCES insulators. Unlike the poor gas-sensing performance of intrinsic NiWO₄, $Fe_{0.5}Ni_{0.5}WO_4$ exhibits a significant NO₂ response (R_{α}/R_{a}) of 11 at 200°C than other gases and a limit of detection (LOD) of 46.4 ppb. This study provides a pathway for realizing gas-sensing performance in strongly correlated electron insulators with large band gaps through the introduction of dopant levels at the cation sites.

KEYWORDS

metal oxide, NiWO₄, gas sensor, NO₂ gas, SCES

1 Introduction

Strongly correlated electron systems (SCES) are characterized by Coulombic repulsion between neighboring cations within a crystal structure, leading to the development of exotic physical properties (Dagotto, 2005; Jacqueline et al., 2022; Zewei et al., 2018; Sami et al., 2022; Morosan et al., 2012; Bhargava et al., 2020; Watthaisong et al., 2019; Cesare et al., 2021; You et al., 2016; Park et al., 2020). One notable feature of SCES is the presence of a pseudo-band gap, often referred to as the Mott gap, which arises due to strong Coulombic repulsion between cations, as commonly observed in NiO. The size of this pseudo-band gap depends on the Hubbard parameter (U) for each cation, as indicated by theoretical calculations. Additionally, SCES typically exhibit magnetic ordering, often in the form of antiparallel spin alignment, with net magnetization being influenced by the Coulombic repulsion between magnetic cations. However, the higher activation energy for electrical transport in SCES insulators, which typically follows the polaronic hopping conduction model, results in a strong insulating behavior, making these materials challenging for a wide range of applications. Consequently, inherited properties governed by Coulombic repulsion in SCES insulators have inspired various strategies aimed at modulating the interactions between cations.

Among the various strategies for tuning SCES properties, we focus on NiWO₄, which exhibits Coulombic repulsion between Ni cations similar to the Mott-insulator behavior observed in NiO (Han et al., 2024; Lee et al., 2024). Theoretical calculations show that a pseudo-gap develops as the U value increases, reaching nearly 6 eV of U_{Ni}, a value that aligns with the experimentally measured band gap obtained from UV-vis spectroscopy. Additionally, calculation results are supported by the neutron diffraction results of NiWO₄, confirming the antiparallel spin ordering between Ni cations (Prosnikov et al., 2017). However, NiWO₄ possesses a monoclinic crystal structure, which has lower symmetry compared to the cubic structure of NiO, and it includes tungsten as an additional component. This provides an extra degree of freedom for tailoring the correlation effects, making it a promising candidate for various applications. For instance, substituting vanadium (V) into the Ni sites, which reduces the Coulombic repulsion strength between cations, could enhance chemical adsorption sites, suggesting the potential of NiWO4 for diverse catalytic applications (Suh et al., 2024).

The chemoresistive type of gas sensor exemplifies an intersectional application of physical and chemical properties (Wang et al., 2018; Kim et al., 2023; Dey, 2018; Choi et al., 2021; Yamazoe, 2005; Lee et al., 2023; Jin et al., 2022; Chen et al., 2013; Franco et al., 2022; Ji et al., 2019). For optimal performance, such a sensor must ensure high and monotonic adsorption of gas molecules at specific sites on the material surface. This adsorption leads to the development of surface depletion or accumulation layers due to the exchange of charge carriers between the analyte gases and the material surface. The type of gas molecules (whether reducing or oxidizing) and the conduction type of the material (n-type or p-type) influence the change in resistance after gas exposure. The resistance then returns to its initial value once the analyte gas molecules desorb from the material surface. To enhance gas sensing functionality, we substitutionally introduced Fe mixed with Ni into NiWO4, which initially exhibited poor gas-sensing performance. The Fe cation level, positioned within the band gap and modulating the weaker Coulombic repulsion, resulted in improved NO₂ gas sensing and selectivity. These findings present a strategy for expanding the potential applications of SCES materials beyond gas sensing, which can be achieved by tailoring Coulombic repulsion.

2 Materials and methods

2.1 Material synthesis

The NiWO₄ and Fe_{0.5}Ni_{0.5}WO₄ powders were synthesized using a solid-state reaction. High-purity Fe₂O₃ (Kojundo Chemical Lab, 99.9%), NiO (Kojundo Chemical Lab, 99.97%), and WO₃ (Kojundo Chemical Lab, 99.9%) powders were mixed following the nominal atomic ratio of NiWO₄ and Fe_{0.5}Ni_{0.5}WO₄ in an alumina mortar with ethanol for wet mixing. The mixed powders underwent heat treatment in an electric box furnace at 900°C for 12 h. The crystal structure characterization of the synthesized powders was performed by X-ray diffraction (XRD, Smart Lab, Rigaku) with Cu K α radiation and Raman spectroscopy (LabRAM ARAMIS, Horiba Jobin Yvon).

2.2 Theoretical calculation

The structural optimization and electronic structure calculations were performed using the density functional theory (DFT), as implemented in the QUANTUM-ESPRESSO (Sandro et al., 2005; Giannozzi et al., 2009; Giannozzi et al., 2017), using the Perdue-Burke-Ernzerhof (PBE) generalized-gradient approximation (GGA) functional (Perdew et al., 1996) and projector augmented wavefunction (PAW) pseudopotentials (Blöchl, 1994). Convergence tests on kinetic-energy cutoff and k-point density showed that the 120 Ry and 4 \times 4 \times 4 Monkhorst-Pack (Monkhorst and Pack, 1976) k-point grid are efficient and accurate enough. The crystal structure (materials project ID: mp-21179) was double along the a-axis to reflect that NiWO₄ has an antiferromagnetic order. The structure was then relaxed to the remaining force, and stress can be less than 10-3 Ry/Bohr and 0.1 kbar. These calculations were performed under the collinear spin-polarized scheme where the spin quantization axis was fixed to the Cartesian z-axis, which is only ~0.0131° off from the crystal c-axis. To consider the correlated nature of NiWO4 appropriately, the Hubbard U repulsion parameters on Ni-3d, Fe-3d, and W-5d were added according to the scheme of Dudarev et al. (1998). Further relaxation of forces and stresses due to the inclusion of Hubbard U parameters were not performed. The Hubbard parameters were calculated self-consistently using the density functional perturbation theory (DFPT), as implemented in the HP code (Timrov et al., 2018; Timrov et al., 2021; Timrov et al., 2022).

2.3 Evaluation of the gas-sensing performance

A two-probe electrode configuration was employed for the gassensing analysis. NiWO4 and Fe0.5Ni0.5WO4 powders were put on the gold electrodes positioned on an alumina substrate with 0.2 mL of ethanol on synthesized powders, and the powder was physically pressed to fix the powder on the substrate. The gas-sensing performance of the fabricated sensors was evaluated within a custom-built chamber equipped with mass flow controllers, maintaining a fixed flow rate of 500 standard cubic centimeters per minute using air as the carrier gas. The sensors were exposed to the target gas concentrations increasing up to 20 ppm for 1,000 s, followed by a recovery period in the air for 500 s at room temperature, 100, and 200°C. The resistance values in air (R_a) and upon exposure to the target gases (Rg) were recorded, and the sensor response (R_g/R_a) was determined by calculating the ratio of the resistance values in ambient air to under the target gas exposure conditions. Gas-sensing measurements were performed for various gases, including NO2, H2S, SO2, benzene, CO, ethanol, and acetone.



3 Results

3.1 Substitutionally located Fe in the Ni site for SCES NiWO $_4$

The NiWO₄ strongly correlated electron system (SCES) exhibits a wolframite-type crystal structure (space group P2/c), composed of corner-shared [NiO₆] and [WO₆] octahedral sublattices, with significant Coulombic repulsion between Ni atoms (Prosnikov et al., 2017; Han et al., 2024; Suh et al., 2024). To modulate the Coulombic repulsion, we replaced Fe cations into the Ni sites of NiWO4 using a solid-state synthesis method, as depicted in Figure 1A. The Fe cations typically exhibit a +2 to +3 oxidation state and have an atomic radius of 1.26 Å, which is similar to that of Ni cations (1.26 Å; +2 to +3 oxidation state). In contrast, W cations have a larger atomic radius of 1.41 Å and an oxidation state of +5 to +6. The same wolframite-type structure of FeWO₄, which also consists of corner-shared [FeO₆] and [WO₆] octahedral sublattices with analogous Wyckoff positions (Maignan et al., 2022), suggests that the Fe cations are substitutionally located in the Ni sites of NiWO₄. Figure 1B shows that both the synthesized NiWO₄ and Fe_{0.5}Ni_{0.5}WO₄ powders exhibit a single phase. Raman spectroscopy results in Figure 1C reveal that these monoclinic structures display 36 distinct Raman vibrational modes, including 8 Ag and 10 Bg active modes. Notably, the Fe0.5Ni0.5WO4 sample shows a downward shift in peak positions compared to NiWO₄, particularly in the Ni–O symmetric vibration mode within [NiO₆], which shifts from 364.8 cm⁻¹ in NiWO₄ to 362.1 cm⁻¹ in Fe_{0.5}Ni_{0.5}WO₄, indicating weaker Ni–O bonding. This peak shift is more pronounced than those observed in the W–O asymmetric vibration mode near 698 cm⁻¹ and the W–O symmetric vibration mode near 890 cm⁻¹. The temperature-dependent magnetization (*M*) curve reveals a Néel temperature (T_N) of 63 K for both NiWO₄ and Fe_{0.5}Ni_{0.5}WO₄ compositions, with Fe_{0.5}Ni_{0.5}WO₄ exhibiting higher magnetization, as shown in Figure 1D, which suggests reduced Coulombic repulsion, which is common in SCES (Park et al., 2020). The XRD and Raman results confirm that Fe is located at the Ni site within the single phase of the NiWO₄ SCES matrix.

To investigate the effect of Fe substitution theoretically, we calculated the electronic structure of NiWO₄ and Fe_{0.5}Ni_{0.5}WO₄ SCES, whose crystal structures are shown in Figure 2A. As reported in many earlier works, the Hubbard *U* scheme can enhance the accuracy of the calculation, especially the band gap. We first assumed 6.0 eV of on-site Coulomb repulsion energy for both Ni 3*d* and W 5*d*. The density functional perturbation theory (DFPT) calculation of Hubbard parameters was then performed on this ground state using a gamma-only *q*-point mesh. This DFPT calculation yielded U = 6.5951 eV for Ni-3*d* and 3.4487 eV for W 5*d*. A new ground state with U = 6.6 eV for Ni-3*d* and U = 3.4 eV for W-5*d* was calculated. We again performed the DFPT calculation



Theoretical results of NiWO₄ and Fe_{0.5}Ni_{0.5}WO₄ SCES. (**A**) Model structure of NiWO₄ (top) and Fe_{0.5}Ni_{0.5}WO₄ (bottom) from the DFT calculations. (**B**, **C**) Electronic structure of NiWO₄ of DOS (U = 0) and PDOS plots ($U_{Nii} = 6.6 \text{ eV}$; $U_W = 3.4 \text{ eV}$) (**B**) and band structure with the considered U value (**C**). (**D**, **E**) Electronic structure of Fe_{0.5}Ni_{0.5}WO₄. The DOS and PDOS plots (**D**) and the band structure with the U value (**E**).

TABLE 1 Calculated Hubbard parameters of each atom in eV.	The values on the right in each cell of U represent the calculated Hubbard parameter wher
DFPT is applied to the ground state of the value on the left.	

Iteration	U _{Ni}	U _{Fe}	Uw
NiWO4			
1	6.0 6.5951	—	3.4 3.4487
2	6.6 6.5727	_	3.4 3.4571
$2, q = 1 \times 2 \times 2$	6.6 6.6125	—	3.4 3.4668
$2, q = 2 \times 4 \times 4$	6.6 6.6143	_	3.4 3.4669
Fe _{0.5} Ni _{0.5} WO ₄			
1	6.9 6.3946	6.9 6.3772	3.5 3.4960
2	6.4 6.4320	6.4 6.4338	3.5 3.4718
$2, q = 1 \times 2 \times 2$	6.4 6.4731	6.4 6.5612	3.5 3.4865
$2, q = 2 \times 4 \times 4$	6.4 6.4740	6.4 6.5763	3.5 3.4875
$3, q = 2 \times 4 \times 4$	6.5 6.4651	6.6 6.5522	3.5 3.4858

of Hubbard parameters, which resulted in quite converged values of U = 6.5727 eV for Ni-3*d* and U = 3.4561 eV for W-5*d*. Finally, we checked the dependency of the Hubbard parameters on the *q*-point mesh size. The DFPT calculations of *U* on the ground state with U = 6.6 eV for Ni-3d and U = 3.4 eV for W-5*d* were performed using *q*-point mesh of sizes of $1 \times 2 \times 2$ and $2 \times 4 \times 4$. As the *q*-point size increases, *U* parameters also increase, but it does not vary much, showing a difference of *U* less than ~0.1 eV, as seen in Table 1,

implying that the parameters are well-converged. The ground state with these self-consistently converged *U* parameters shows an indirect optical band gap of 2.98 eV, as shown in Figures 2B, C, which agrees well with some earlier results (Shepard and Smeu, 2018; Errandonea et al., 2023; Ye et al., 2023). We performed the same procedures to calculate the Hubbard parameters (Table 1), density of states (DOS), and the band structure of $Fe_{0.5}Ni_{0.5}WO_4$ (Figures 2D, E). We supposed identical *U* values for two Ni atoms



and two Fe atoms due to their structural symmetry. The converged values slightly differ from the value of NiWO₄, but it rapidly converged, as iterated. The test for convergence on the q mesh revealed that the calculation with the gamma-point only has a small deviation. This deviation was reduced to less than 0.05 eV by an additional iteration. The correction with this converged U value modifies DOS remarkably, as shown in Figure 2D, showing that the system is strongly correlated. In addition, states mainly consisting of Fe-3d and O-2p appear near the Fermi energy. This contrasts that the states of NiWO₄ near the Fermi energy mainly consist of Ni-3d and O-2p (Errandonea et al., 2023). These observations imply the remarkable alteration of the conduction mechanism and characteristic in Fe_{0.5}Ni_{0.5}WO₄.

Summarizing the structure of Fe0.5Ni0.5WO4 from the experimental and theoretical results above, it maintains the wolframite-type crystal structure while modulating the Coulombic repulsion between Ni atoms, as evidenced by the crystal structure distortion and enhanced magnetic properties compared to NiWO4. Experimentally, the relatively higher Raman shift of the [NiO₆] symmetric vibration mode, compared to the [WO₆] vibration modes, indicates that Fe atoms preferentially occupy the Ni sites, leading to a distorted Ni-O bonding state. Additionally, the higher magnetization of Fe0.5Ni0.5WO4, in contrast to the antiferromagnetic phase of NiWO₄, is attributed to the higher magnetic moment of Fe. Moreover, the presence of Fe states near the Fermi level (E_F) and within a 3.1-eV large depletion region, as suggested by the DFT results, indicates improved carrier transfer compared to NiWO₄. The following section demonstrates the emergence of gas-sensing performance in Fe0.5Ni0.5WO4, in contrast to the lack of gas-sensing functionality in NiWO4, as induced by the Fe dopant.

3.2 Emerging NO_2 gas sensing in $Fe_{0.5}Ni_{0.5}WO_4$

The gas-sensing measurements were conducted using a twoelectrode system, as depicted in Figure 3. The samples were prepared by pressing the synthesized powder onto an Au-coated Al_2O_3 substrate, followed by the addition of a few drops of ethanol. The samples were then heat-treated to vaporize the ethanol and secure the material onto the substrate. The gas sensing tests were performed

under a 20-ppm concentration of various gases, including NO₂, H₂S, H₂, SO₂, CO, benzene, ethanol, and acetone, at room temperature, 100°C, or 200°C. The results for NO₂ and H₂S gas responses from $Fe_{0.5}Ni_{0.5}WO_4$, shown in Figures 4A, B, indicate a significantly higher gas-sensing response at 200°C compared to that at RT and 100°C, highlighting this as the optimal operational temperature. A comparison of the gas-sensing responses between NiWO4 and Fe0.5Ni0.5WO4 reveals substantial differences in performance. For NO_2 detection, $\mathrm{Fe}_{0.5}\mathrm{Ni}_{0.5}\mathrm{WO}_4$ exhibits a notable increase in resistance compared to the air environment, confirming that both Fe0.5Ni0.5WO4 and NiWO4 SCES function as p-type gas sensing materials. In contrast, NiWO₄ samples consistently demonstrated a low and nearly uniform response, with an absolute value of gas sensing response $(R_g/R_a \text{ or } R_a/R_g)$ close to 2 for all tested analyte gases, as shown in Figures 4A-H. However, Fe_{0.5}Ni_{0.5}WO₄ displayed a significantly enhanced gas-sensing response, with an Rg/Ra value of 10.4 under exposure to NO2 gas, marking it as the highest response among the tested gases. The second highest response was under H₂S exposure, with a 2.8 response, which is still notably higher than the near 2 response observed for other gases such as H2, SO2, CO, benzene, ethanol, and acetone. The gas selectivity plot in Figure 4I further confirms the superior selectivity of Fe_{0.5}Ni_{0.5}WO₄ for NO₂. Figure 4J shows the comparison of NO₂ responses at various Fe concentrations measured at different temperatures, including room temperature (RT), 100°C, and 200°C. Although Fe0.5Ni0.5WO4 exhibited a significant response of 11 at 200°C, Fe_{0.25}Ni_{0.75}WO₄ and Fe_{0.4}Ni_{0.6}WO₄ showed negligible gas-sensing responses across all measured temperatures. The higher gas-sensing performance of Fe0.5Ni0.5WO4 highlights the optimized Fe concentration and operating temperature as critical combined factors that enhance adsorption and facilitate carrier transfer between the gas molecules and the surface.

Furthermore, the gas-sensing response to varying NO_2 concentrations is illustrated in Figures 5A, B. As the NO_2 concentration decreases from 20 ppm to 1 ppm, a corresponding decline in gas response is observed, which is particularly noticeable between the concentrations of 10 ppm and 1 ppm. However, the response saturated at 10 ppm and 20 ppm of NO_2 , indicating a plateau in sensor performance at these levels. To further quantify the sensor's sensitivity, we calculated the LOD based on the responses at NO_2 concentrations of 10 ppm, 4 ppm, 2 ppm, and 1 ppm. From this analysis, an LOD of 46.4 ppb was determined. This value



FIGURE 4

Gas-sensing results of NiWO₄ and Fe_{0.5}Ni_{0.5}WO₄ at 200°C under 20 ppm of different gases. (A) NO₂ at RT, 100°C, and 200°C, respectively. (B) H₂S at RT, 100°C, and 200°C. (C) H₂. (D) SO₂. (E) CO. (F) Benzene. (G) Ethanol. (H) Acetone. (I) Results of gas selectivity. (J) Comparison of the responses under an NO₂ environment and different temperatures using Fe_{0.25}Ni_{0.75}WO₄ and Fe_{0.4}Ni_{0.6}WO₄.



underscores the sensor's capability to detect trace amounts of NO₂ with significant precision. The ability to achieve such a low LOD highlights the effectiveness of $Fe_{0.5}Ni_{0.5}WO_4$, which develops the material's gas-sensing performance, particularly at lower concentrations. These results underscore the effectiveness of Fe doping in NiWO₄, particularly in enhancing NO₂ gas-sensing performance at 200°C. The distinct difference in response between NiWO₄ and $Fe_{0.5}Ni_{0.5}WO_4$ highlights the critical role of Fe cations in modulating the gas-sensing properties, suggesting that the Fe dopant level could serve as an activating agent for the gas

adsorption site and improved the charge carrier transfer for selective gas-sensing materials and various chemistry applications.

4 Conclusion

The Fe dopant level located at band gap is used for enhancing the gas-sensing functionality on the NiWO₄ SCES insulator, which shows negligible gas-sensitivity at 200°C for all measured gas molecules. The Coulombic repulsion between magnetic cations in

NiWO₄ open over 3.0 eV of the band gap, and dopant-level Fe is manipulated via being substitutionally located in the Ni site that developed 10.4 R_g/R_a under 20 ppm of an NO₂ environment. The Fe dopant implies playing an important role, such as activating the higher gas adsorption site or the higher carrier transferring from the charge carrier density changed between analyte gas molecules and materials' surface. These results encourage the use of further chemical sensing devices on SCES insulators by modulating the Coulombic repulsion between magnetic cations and dopant levelsupporting at the Mott gap.

Data availability statement

The raw data in this manuscript will be available on request.

Author contributions

JL: Formal analysis, Methodology, Writing-review and editing. SK: Formal analysis, Methodology, Writing-review and editing. GP: Formal analysis, Investigation, Methodology, Writing-original draft. MK: Formal analysis, Investigation, Methodology, Writing-original draft. SJ: Methodology, Writing-original draft. HC: Data curation, Writing-original draft. GH: Data curation, Writing-original draft. JH: Methodology, Writing-original draft. SL: Conceptualization, Writing-original draft, Writing-review and editing. KL: Conceptualization, Writing-original draft, Writing-review and editing.

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Conflict of interest

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